10.1071/ CH05121\_ AC ©CSIRO 2005 Accessory Publication: Aust. J. Chem., 2005, 58(9), 660–663.

 $1 \mathrm{H}$ 

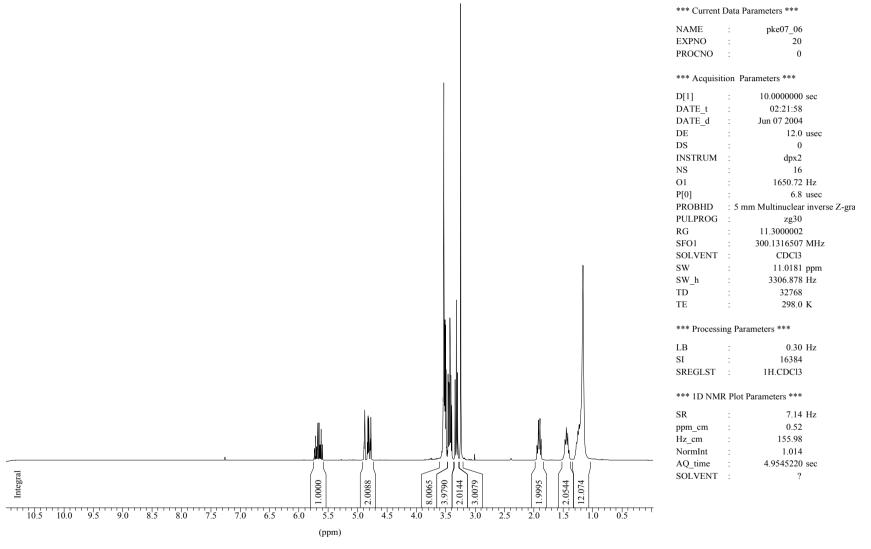


Figure S1. <sup>1</sup>H NMR spectrum of 11-(2-(2-(2-methoxy)ethoxy)ethoxy)undec-1-ene (1).

Alternative fit for the C1s XP narrow scan

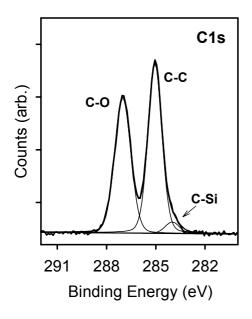


Figure S2. XP narrow scans of the carbon 1s region of Si(111) derivatized with  $C_{11}EO_3Me$ .

Alternatively to the fit shown in the paper, the C1s narrow scan could be deconvoluted into three peaks corresponding to the C-O (287.0 eV), C-C (285.0 eV) and C-Si (283.9 eV) species. The area of the C-Si peak was consistent with expectation when taking the attenuation due to the overlying monolayer into account. The ratio of C-O bonded carbons to the remaining carbons of the molecule was essentially the same as that determined from the fit shown in the paper.

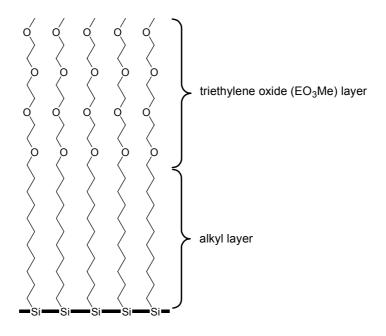


Figure S3. Bilayer model of the Si-C linked monolayer. The photoelectrons from the top  $(EO_3Me)$  layer are attenuated within the top layer itself. The photoelectrons from the bottom (alkyl) layer are attenuated within the bottom layer itself and also attenuated by the top layer.

#### Correction of peak areas for attenuation

The basis of the following considerations to calculate the expected ratio of the peak area at 285.0 eV (C-C linked carbons) to that at 287.0 eV (C-O linked carbons) is a "bilayer" model of the monolayer (Fig. S2). In this model the triethylene oxide moieties form a separate "layer" on top the alkyl "layer", i.e. there is no intermixing of the two different moieties.

### (a) Attenuation of photoelectrons from C-O linked carbon

The intensity of photoelectrons originating from the C-O linked carbons,  $S_{EO}^{C}$ , is attenuated within the layer and the area of the corresponding XPS signal is given by

$$S_{EO}^{C} = C \sigma_{C} \rho_{EO}^{C} \lambda_{EO}^{C} A \left(1 - e^{-(d_{EO}/\lambda_{EO}^{C}\sin\theta)}\right)$$
(1)

where:

C is an instrument specific factor,

 $\sigma_{\rm c}$  is the sensitivity factor for carbon,

 $\rho_{\rm EO}^{\rm C}$  is the density of carbon atoms per unit area in the triethylene oxide layer,

 $\lambda_{EO}^{C}$  is the inelastic mean free path of photoelectrons derived from carbon in the triethylene oxide layer,

A is the area probed by the X-ray beam,

 $d_{EO}$  is the thickness of the triethylene oxide layer, here we assume  $d_{EO}$  to be between 6-8 Å,

 $\theta$  is the angle between the analyzer and the surface (90° for the instrument used in this study).

The peak area without attenuation is equal to

$$S_{EO}^{C,unattenuated} = C \,\sigma_C \,\rho_{EO}^C \,A \,d_{EO} \tag{2}$$

The measured peak area for the peak at 287.0 eV is therefore multiplied by the following factor to account for the attenuation within the triethylene oxide layer:

$$f_{EO} = S_{EO}^{C,unattenuated} / S_{EO}^{C} = d_{EO} / [\lambda_{EO}^{C} (1 - e^{-(d_{EO}/\lambda_{EO}^{C}\sin\theta)})]$$
(3)

#### (b) Attenuation of photoelectrons from C-C linked carbon

The intensity of the photoelectrons from the C-C linked carbons,  $S_{alkyl}^{C}$ , of the alkyl chains is attenuated by the overlying triethylene oxide layer as well as within the alkyl layer itself. The peak area is given by

$$S_{alkyl}^{C} = C \ e^{-(d_{EO}/\lambda_{EO}^{C}\sin\theta)} \ \sigma_{C} \ \rho_{alkyl}^{C} \ \lambda_{alkyl}^{C} \ A \left(1 - e^{-(d_{alkyl}/\lambda_{alkyl}^{C}\sin\theta)}\right), \tag{4}$$

where:

 $\rho_{alkyl}^{C}$  is the density of carbon atoms per unit area in the alkyl layer,  $\lambda_{alkyl}^{C}$  is the inelastic mean free path of photoelectrons derived from carbon in the alkyl layer,  $d_{alkyl}$  is the thickness of the alkyl layer, here we assume  $d_{alkyl} = 9-10$  Å.

The corresponding correction factor is then given by

$$f_{alkyl} = \frac{S_{alkyl}^{C,unattenuated}}{S_{alkyl}^{C}} = \frac{d_{alkyl}}{e^{-(d_{EO}/\lambda_{EO}^{C}\sin\theta)} \lambda_{alkyl}^{C} (1 - e^{-(d_{alkyl}/\lambda_{alkyl}^{C}\sin\theta)})}$$
(5)

#### (c) Estimation of the inelastic mean free path

The inelastic mean free path  $\lambda_k^j$  is given by [1]

$$\lambda_k^j = \rho_k^{-1} \left( 49 \, E_k^{-2} + 0.11 \, E_k^{0.5} \right), \tag{6}$$

where  $E_k$  is the kinetic energy of the photoelectron, and  $\rho_k$  is the density of the material in layer *k*. The kinetic energy of the photoelectron  $E_k$  can be obtained by

$$E_k = h \nu - E_b \,, \tag{7}$$

where  $E_b$  is the binding energy and  $h\nu$  the X-ray photon energy.

Based on estimated densities for the alkyl layer (0.78 g cm<sup>-3</sup>) and the EO<sub>3</sub>Me layer (1.03 g cm<sup>-3</sup>) the attenuation lengths for the carbon derived photoelectrons in the alkyl monolayer were calculated according to Eq. 6 and 7 to give  $\lambda_{alkyl}^{C} = 49$  Å and  $\lambda_{EO}^{C} = 37$  Å.

## (d) Expected ratio for C-C:C-O peak areas

Multiplication of the number of C-C linked carbons (10) and the number of C-O linked carbons (8) with the corresponding correction factors results in a C-C:C-O ratio of 0.98-1.04:1

# Reference

[1] M. P. Seah and W. A. Dench. Quantitative electron spectroscopy of surfaces: A standard data base for electron inelastic mean free paths in solids. *Surface and Interface Analysis* **1979**, 1, 2-11.